Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
1.253 inches
Overall Diameter:
0.430 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
D0-4
Mounting Method:
Threaded stud
Thready Qty Per Inch (tpi):
32
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 repetitive peak reverse voltage and 1200.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
16.00 amperes collector current, dc
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0